

# 10A, 45V - 150V Schottky Barrier Surface Mount Rectifier

## **FEATURES**

- Low power loss, high efficiency
- Ideal for automated placement
- Guard ring for overvoltage protection
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

## **APPLICATIONS**

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

#### **MECHANICAL DATA**

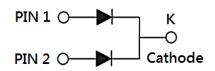
- Case: TO-263AB (D<sup>2</sup>PAK)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: As marked
- Weight: 1.37g (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I <sub>F</sub>	10	А		
V <sub>RRM</sub>	45 - 150	V		
I <sub>FSM</sub>	120	А		
T <sub>J MAX</sub>	150	°C		
Package	TO-263AB (D <sup>2</sup> PAK)			
Configuration	Dual dies			





TO-263AB (D<sup>2</sup>PAK)



		MBRS	MBRS	MBRS	MBRS	
PARAMETER	SYMBOL	1045	1060	10100	10150	UNIT
		CT-Y	CT-Y	CT-Y	CT-Y	
Marking code on the device		MBRS 1045CT	MBRS 1060CT	MBRS 10100CT	MBRS 10150CT	
Repetitive peak reverse voltage	V <sub>RRM</sub>	45	60	100	150	V
Reverse voltage, total rms value	V <sub>R(RMS)</sub>	31	42	70	105	V
Forward current	I <sub>F</sub>	10		Α		
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I <sub>FSM</sub>	120		Α		
Peak repetitive reverse surge current <sup>(1)</sup>	I <sub>RRM</sub> 1			Α		
Peak repetitive forward current (Rated $V_R$ , Square wave, 20KHz)	I <sub>FRM</sub>		1	0		А
Critical rate of rise of off-state voltage	dv/dt		10,	000		V/µs
Junction temperature	T <sub>J</sub> -55 to +150			°C		
Storage temperature	T <sub>STG</sub> -55 to +150		°C			

#### Notes:

1. tp = 2.0µs, 1.0KHz



THERMAL PERFORMANCE				
PARAMETER	SYMBOL	ТҮР	UNIT	
Junction-to-case thermal resistance	R <sub>eJC</sub>	2	°C/W	

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^{\circ}C$ unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
	MBRS1045CT-Y	I <sub>F</sub> = 5A, T <sub>J</sub> = 25°C	-	-	0.70	V
	MBRS1060CT-Y			-	0.80	V
	MBRS10100CT-Y			-	0.85	V
	MBRS10150CT-Y			-	0.88	V
	MBRS1045CT-Y			-	0.80	V
	MBRS1060CT-Y	L 404 T 0500		-	0.90	V
	MBRS10100CT-Y	$I_F = 10A, T_J = 25^{\circ}C$	-	-	0.95	V
Forward voltage per	MBRS10150CT-Y			-	0.98	V
diode <sup>(1)</sup>	MBRS1045CT-Y		V <sub>F</sub>	-	0.57	V
	MBRS1060CT-Y	I <sub>F</sub> = 5A, T <sub>J</sub> = 125°C	-	-	0.65	V
	MBRS10100CT-Y			-	0.75	V
	MBRS10150CT-Y			-	0.78	V
	MBRS1045CT-Y	I <sub>F</sub> = 10A, T <sub>J</sub> = 125°C		-	0.67	V
	MBRS1060CT-Y			-	0.75	V
	MBRS10100CT-Y			-	0.85	V
	MBRS10150CT-Y			-	0.88	V
Reverse current @ rated V <sub>R</sub> per diode <sup>(2)</sup>	MBRS1045CT-Y MBRS1060CT-Y MBRS10100CT-Y MBRS10150CT-Y	T <sub>J</sub> = 25°C		-	100	μΑ
	MBRS1045CT-Y		I <sub>R</sub>	-	15	mA
	MBRS1060CT-Y	T <sub>J</sub> = 100°C		-	10	mA
	MBRS10100CT-Y MBRS10150CT-Y	0		-	-	mA
	MBRS1045CT-Y MBRS1060CT-Y	T <sub>J</sub> = 125°C		-	-	mA
	MBRS10100CT-Y MBRS10150CT-Y			-	5	mA

#### Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION				
ORDERING CODE <sup>(1)</sup>	PACKAGE	PACKING		
MBRS10xCT-Y	TO-263AB (D <sup>2</sup> PAK)	800 / Tape & Reel		

#### Notes:

1. "x" defines voltage from 45V(MBRS1045CT-Y) to 150V(MBRS10150CT-Y)



INSTANTANEOUS REVERSE CURRENT (mA)

**Fig.2 Typical Junction Capacitance** 

Taiwan Semiconductor

## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

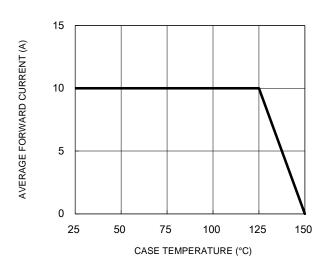
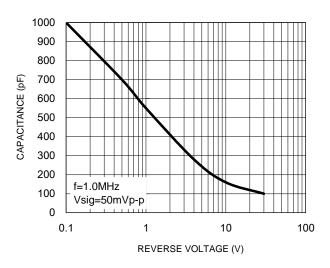
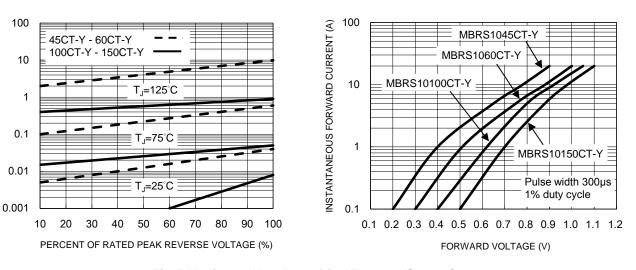


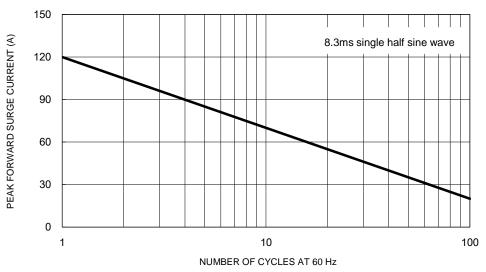
Fig.1 Forward Current Derating Curve

#### **Fig.3 Typical Reverse Characteristics**



## Fig.4 Typical Forward Characteristics



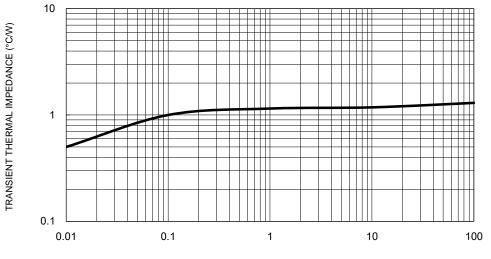


## Fig.5 Maximum Non-Repetitive Forward Surge Current



## **CHARACTERISTICS CURVES**

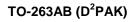
 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

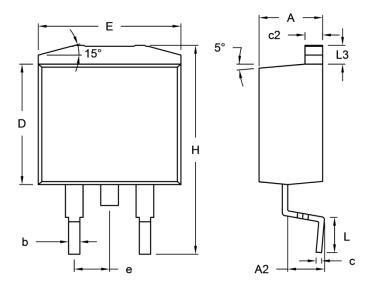


#### Fig.6 Typical Transient Thermal Impedance

PULSE DURATION (s)

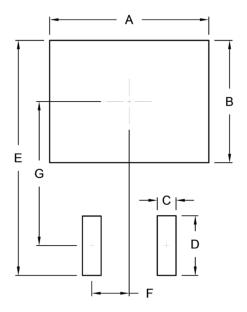
## PACKAGE OUTLINE DIMENSIONS





DIM.	Unit (mm)		Unit (	(inch)	
	Min.	Max.	Min.	Max.	
A	4.44	4.70	0.175	0.185	
A2	2.03	2.79	0.080	0.110	
b	0.68	0.94	0.027	0.037	
с	0.36	0.53	0.014	0.021	
c2	1.14	1.40	0.045	0.055	
D	8.25	9.25	0.325	0.364	
E	-	10.50	-	0.413	
е	2.41	2.67	0.095	0.105	
н	14.60	15.88	0.575	0.625	
L	2.29	2.79	0.090	0.110	
L3	1.14	1.40	0.045	0.055	

## SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	10.80	0.425
В	8.30	0.327
С	1.27	0.050
D	4.05	0.159
E	15.95	0.628
F	2.54	0.100
G	9.775	0.385

## **MARKING DIAGRAM**

S GYWWF
P/N
<b>→</b> → <b>\</b>

P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



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